2. Listing of Items

Applicant(s) sets forth below a list of all patents, publications or other information for consideration by the Office.

GOT, CP31XC)														
2 30 -								Docket Number			Application Number			
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SWC	5	5	5	2	3	3	1	9/3/96	Hsu et al.		437	40	7/11/9	'5
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	4	8	6	8	6	1	9	9/19/89	Mukherjee et al.		365	185	11/21/8	4
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Horiba et al., "A Symmetric Diagonal Driver Transistor SRAM Cell with Imbalance Suppression." IEEE Symmetric on W. St. Tochnology, 1006													.	
Technology for Stable Low Voltage Operation", <u>IEEE Symposium on VLSI Technology 1996</u> , p. 145 Ohshima et al., "Process and Device Technologies For 16Mbit EPROMs With Large-Tilt-Angle Implanted P-pocket Cell", <u>IEDM 1990</u> , pp. 5.2.1 - 5.2.4											<u>y 1990,</u> pp. 144	,-		
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